

YK3407A

P-Channel Enhancement Mode Field Effect Transistor



康比電子
HORNBY ELECTRONIC

General Description

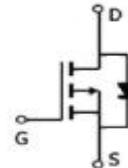
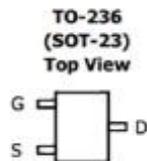
The YK3407A uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

Application

- PWM application
- Load switch
- Power management

Features

- $V_{DS} = -30V, I_D = -4.3A$
 $R_{DS(ON)} < 50m\Omega @ V_{GS} = -10V$
 $R_{DS(ON)} < 80m\Omega @ V_{GS} = -4.5V$
- High power and current handling capability
- Lead free product is acquired
- Surface mount package



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
A7SHB	YK3407A	SOT-23	Ø180mm	8mm	3000 units

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V_{DSS}	-30	V
Gate-Source Voltage	V_{GSS}	± 20	V
Drain Current-Continuous $V_{GS} = -4.5V, @T_A = 25^\circ\text{C}$	I_D	-4.3	A
Drain Current -Pulsed ^{Note1}	I_{DM}	-20	A
Maximum Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	1.5	W
Operating Junction and Storage Temperature Range	T_J	-55 ~ +150	$^\circ\text{C}$

Thermal Characteristics

Thermal Resistance, Junction-to-Ambient ^{Note2}	$R_{\theta JA}$	84	$^\circ\text{C/W}$
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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V, V_{GS}=0V$	-	-	-1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_{DS}=-250\mu A$	-1.1	-1.5	-2.1	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_{DS}=-4.1A$	-	35	50	m Ω
		$V_{GS}=-4.5V, I_{DS}=-3A$	-	50	80	
Forward Transconductance	g_{FS}	$V_{DS}=-5V, I_D=-4.1A$	5.5	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V,$ $f=1.0MHz$	-	700	-	pF
Output Capacitance	C_{oss}		-	120	-	
Reverse Transfer Capacitance	C_{rss}		-	75	-	
Switching Characteristics (Note 4)						
Turn-on Delay Time	$T_{d(on)}$	$V_{DS}=-15V, RL=3.6\Omega$ $V_{GS}=-10V, R_{Gen}=3\Omega$	-	8.5		ns
Turn-on Rise Time	T_r		-	4.8		
Turn-Off Delay Time	$T_{d(OFF)}$		-	28		
Turn-Off Fall Time	T_f		-	12.5		
Total Gate Charge	Q_g	$V_{DS}=-15V, I_D=-4A, V_{GS}=-10V$	-	13	-	nC
Gate-Source Charge	Q_{gs}		-	3	-	
Gate-Drain Charge	Q_{gd}		-	2.9	-	
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	$I_S=4.3A, V_{GS}=0V$ $T_j=25^\circ C$	-	-	-1.2	V

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production

Typical Electrical and Thermal Characteristics

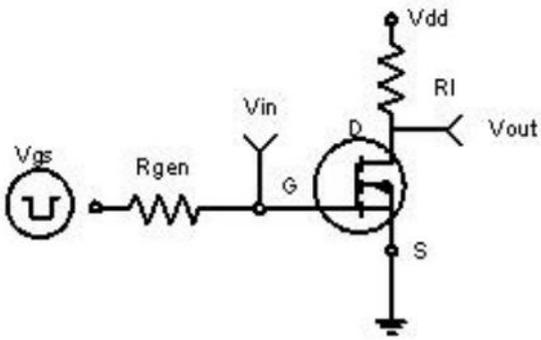


Figure 1: Switching Test Circuit

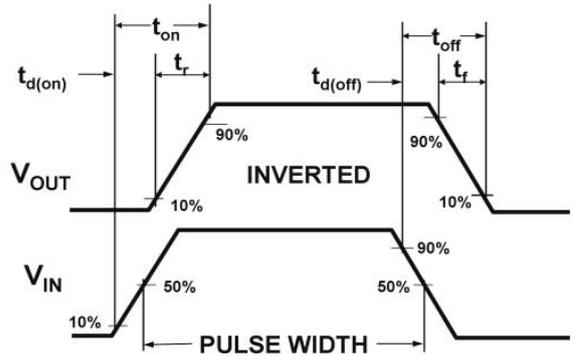


Figure 2: Switching Waveforms

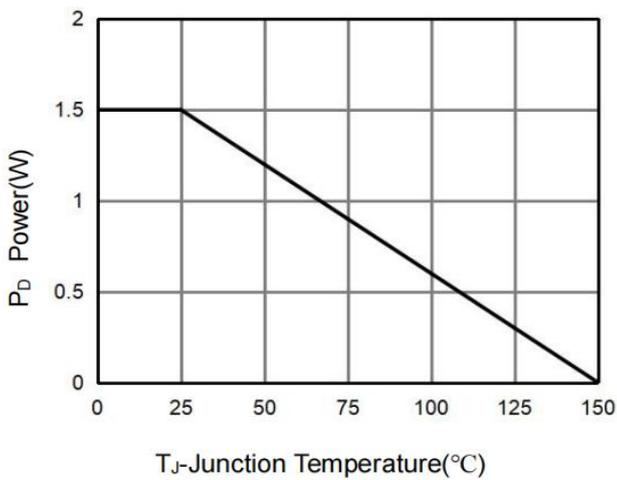


Figure 3 Power Dissipation

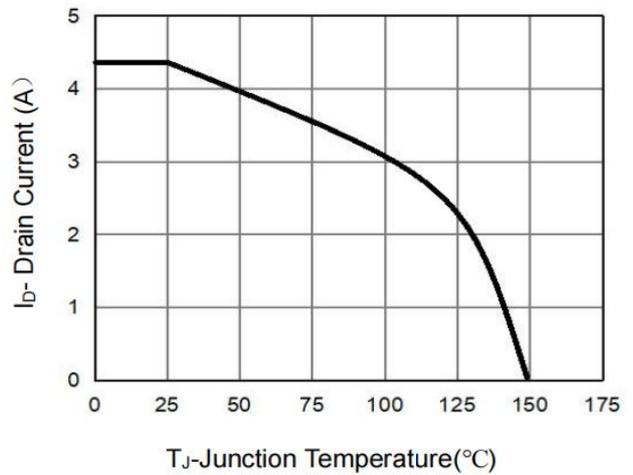


Figure 4 Drain Current

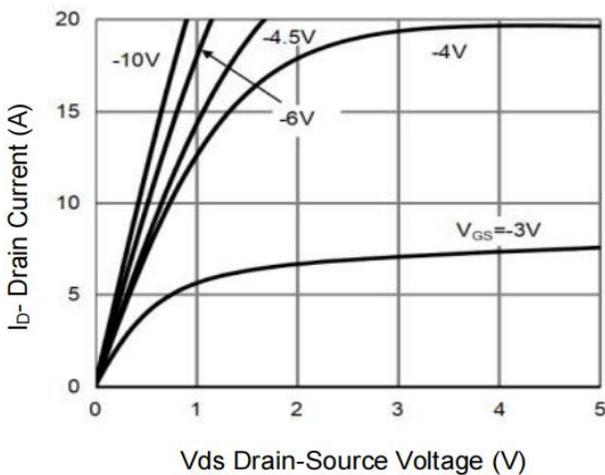


Figure 5 Output Characteristics

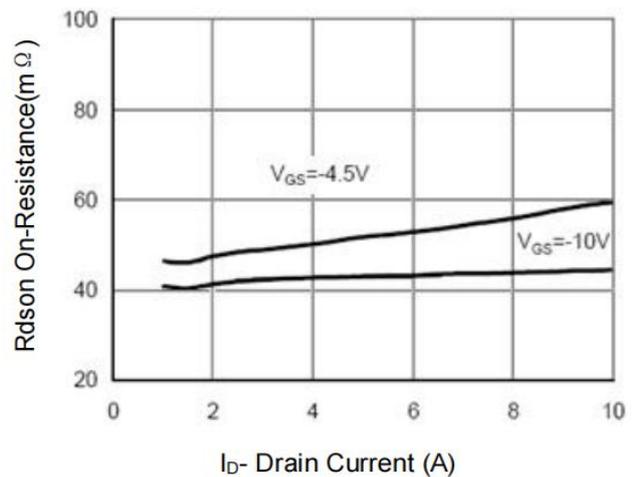


Figure 6 Drain-Source On-Resistance

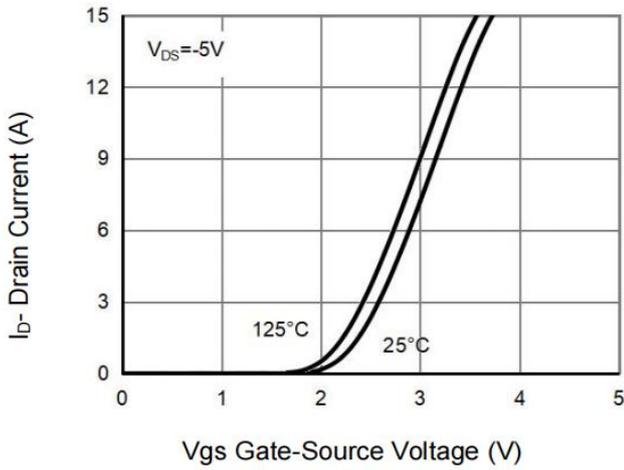


Figure 7 Transfer Characteristics

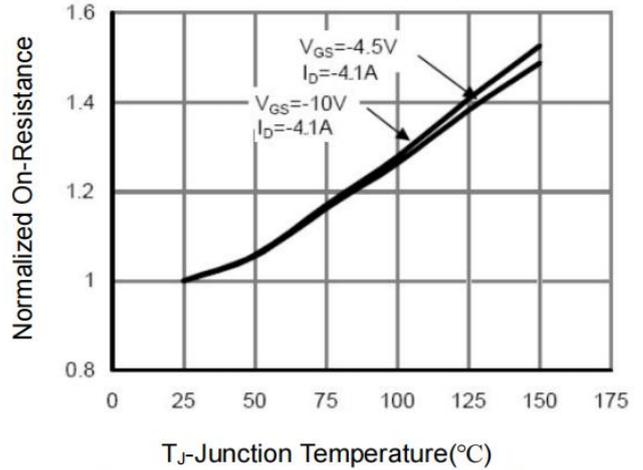


Figure 8 Drain-Source On-Resistance

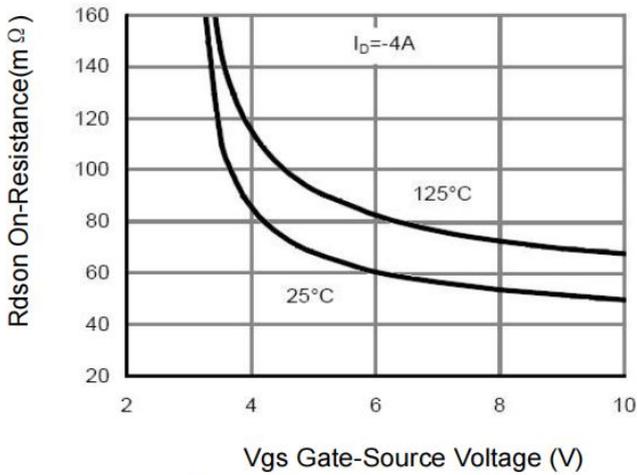


Figure 9 $R_{DS(on)}$ vs V_{GS}

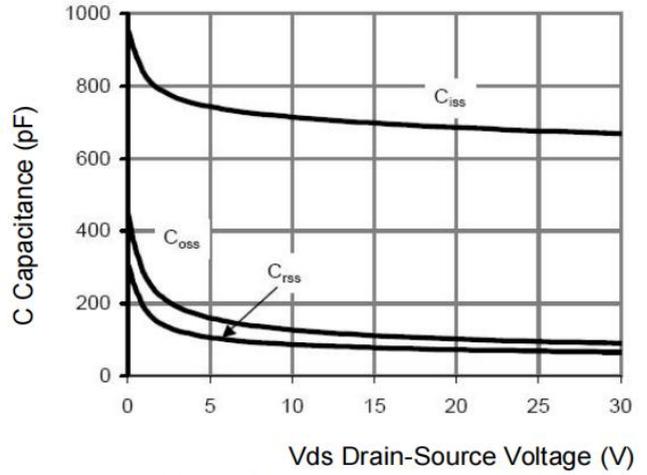


Figure 10 Capacitance vs V_{DS}

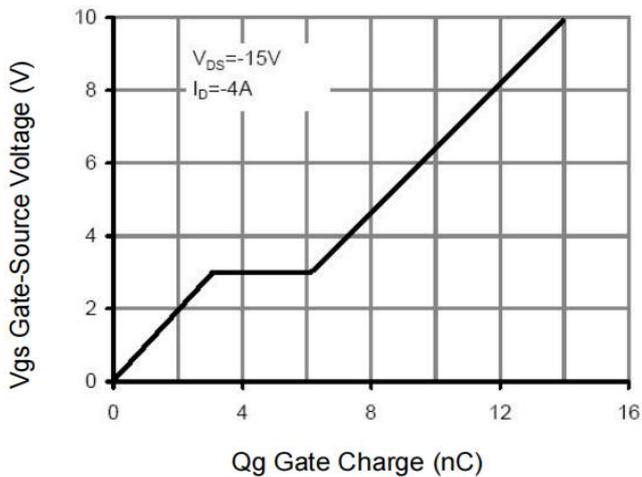


Figure 11 Gate Charge

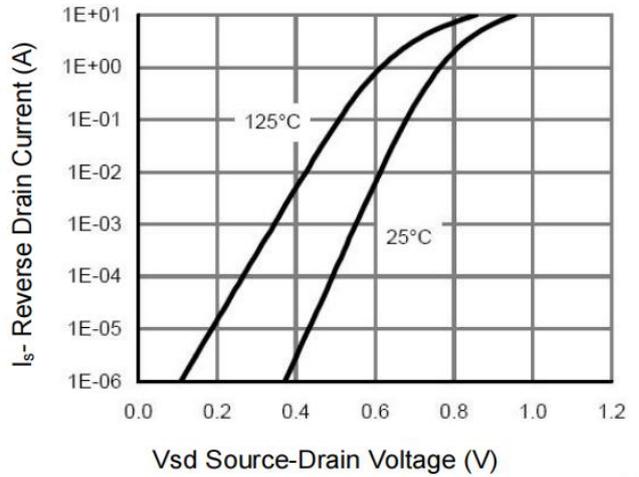


Figure 12 Source- Drain Diode Forward

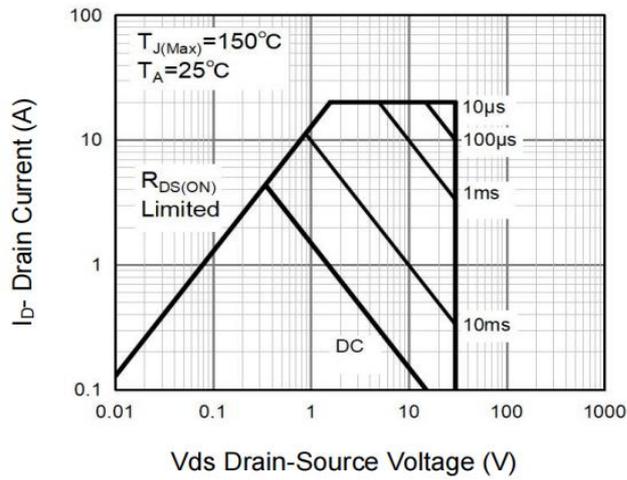


Figure 13 Safe Operation Area

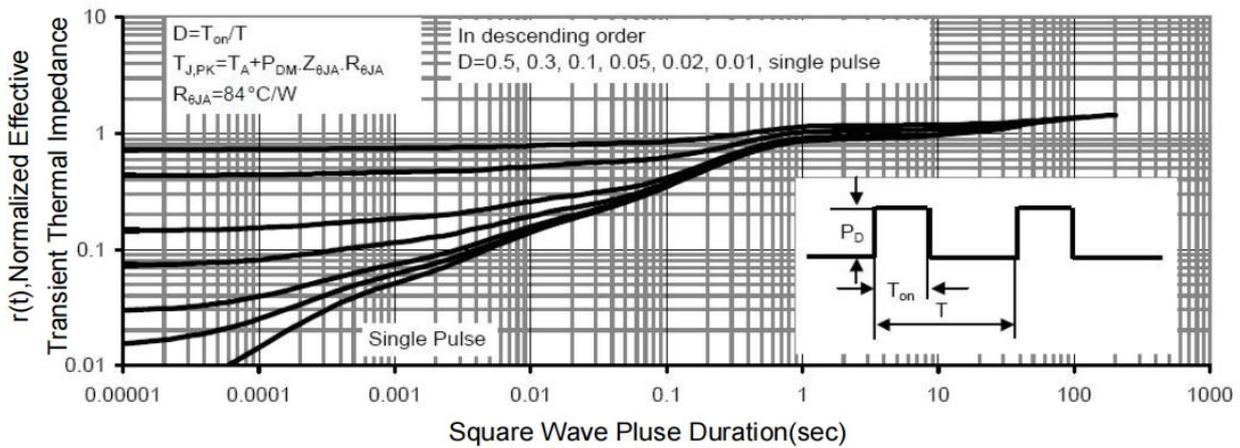


Figure 14 Normalized Maximum Transient Thermal Impedance

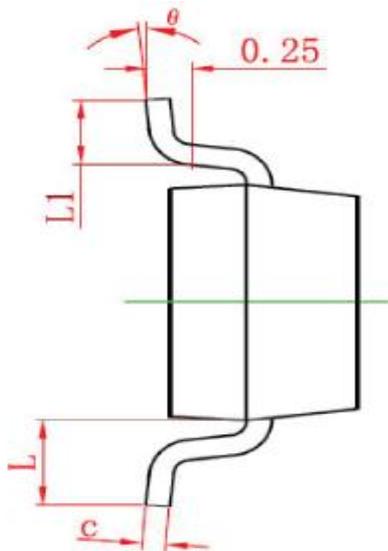
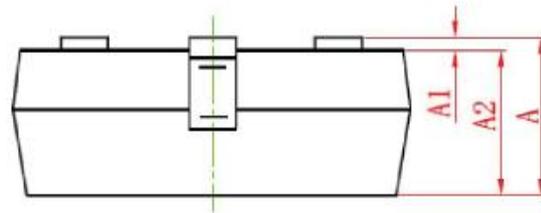
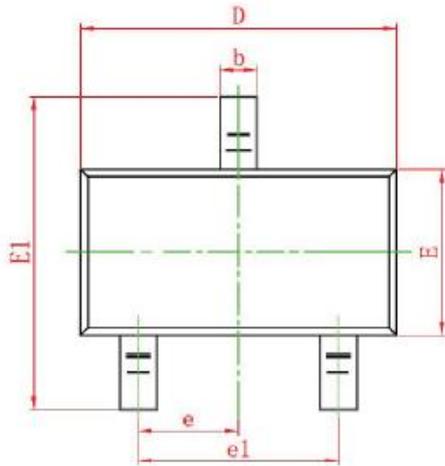
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SOT-23 Package Information



Symbol	Dimensions in Millimeters	
	MIN	MAX
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
C	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950 TYP	
e1	1.800	2.000
L	0.550 REF	
L1	0.300	0.500
θ	0°	8°